

P6SMB-E Series



OBSOLETE DATE: 08/21/202 PCN/ECN# 41356
REPLACED BY: P6SMB

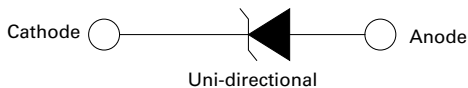


Maximum Ratings and Thermal Characteristics
($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at $T_A=25^\circ\text{C}$ by 10/1000 μs Waveform (Fig.2)(Note 1), (Note 2)	P_{PPM}	600	W
Power Dissipation on Infinite Heat Sink at $T_L=50^\circ\text{C}$	P_D	5.0	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I_{FSM}	100	A
Maximum Instantaneous Forward Voltage at 50A for Unidirectional Only	V_F	3.5	V
Operating Temperature Range	T_J	-65 to 150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to 175	$^\circ\text{C}$
Typical Thermal Resistance Junction to Lead	R_{JL}	20	$^\circ\text{C/W}$
Typical Thermal Resistance Junction to Ambient	R_{JA}	100	$^\circ\text{C/W}$

- Notes:**
1. Non-repetitive current pulse, per Fig. 4 and derated above T_J (initial) = 25°C per Fig. 3.
 2. Mounted on copper pad area of 0.2x0.2" (5.0 x 5.0mm) to each terminal.
 3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only, duty cycle=4 per minute maximum.

Functional Diagram



Description

The P6SMB-E series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

Features

- Excellent clamping capability
- Low incremental surge resistance
- For surface mounted applications to optimize board space
- Low profile package
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC 61000-4-2 ESD 30kV(Air), 30kV (Contact)
- EFT protection of data lines in accordance with IEC 61000-4-4
- Built-in strain relief
- Fast response time: typically less than 1.0ps from 0V to BV min
- 600W peak pulse power capability at 10/1000 μs waveform, repetition rate (duty cycles):0.01 %
- High temperature to reflow soldering guaranteed: 260 $^\circ\text{C}$ /40sec
- $V_{BR} @ T_J = V_{BR} @ 25^\circ\text{C} \times (1 + \alpha T \times (T_J - 25))$ (α T: Temperature Coefficient, typical value is 0.1%)
- EPI silicon technology
- Meet MSL level1, per J-STD-020C, LF maximum peak of 260 $^\circ\text{C}$
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

Applications

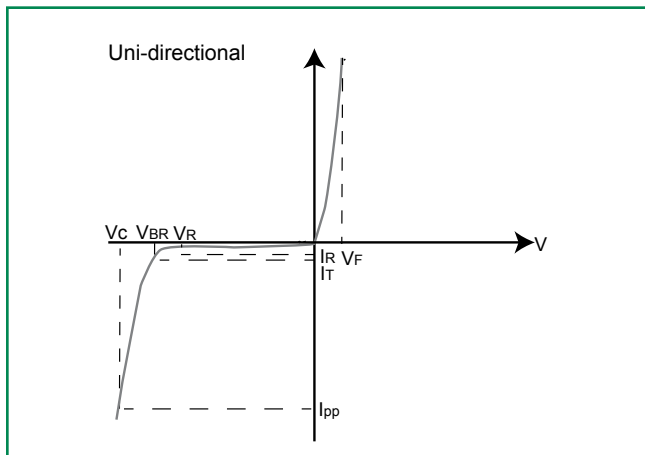
TVS devices are ideal for the protection of I/O Interfaces, V_{CC} bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Part Number (Uni)	Marking	Reverse Stand off Voltage V_R (Volts)	Breakdown Voltage V_{BR} (Volts) @ I_T		Test Current I_T (mA)	Maximum Clamping Voltage V_C @ I_{pp} (V)	Maximum Peak Pulse Current I_{pp} (A)	Maximum Reverse Leakage I_R @ V_R (μA)
			MIN	MAX				
P6SMB350A-E	350S	300	332.0	368.0	1	482.0	1.30	1
P6SMB400A-E	400S	342	380.0	420.0	1	548.0	1.10	1
P6SMB440A-E	440S	376	418.0	462.0	1	602.0	1.00	1
P6SMB480A-E*	480S	408	456.0	504.0	1	658.0	0.95	1
P6SMB510A-E*	510S	434	485.0	535.0	1	698.0	0.86	1
P6SMB530A-E*	530S	451	503.5	556.5	1	725.0	0.83	1
P6SMB540A-E*	540S	460	513.0	567.0	1	740.0	0.82	1
P6SMB550A-E*	550S	468	522.5	577.5	1	760.0	0.79	1
P6SMB600A-E*	600S	510	570.0	630.0	1	822.0	0.73	1
P6SMB650A-E*	650S	553	617.5	682.5	1	891.0	0.68	1
P6SMB700A-E*	700S	595	665.0	735.0	1	959.0	0.63	1
P6SMB800A-E*	800S	680	760.0	840.0	1	1096.0	0.55	1
P6SMB900A-E*	900S	765	855.0	945.0	1	1233.0	0.50	1
P6SMB1000A-E*	1000S	850	950.0	1050.0	1	1365.0	0.44	1

Note: for parts with * are still under development

I-V Curve Characteristics



- P_{PPM} Peak Pulse Power Dissipation** – Max power dissipation
- V_R Stand-off Voltage** – Maximum voltage that can be applied to the TVS without operation
- V_{BR} Breakdown Voltage** – Maximum voltage that flows though the TVS at a specified test current (I_T)
- V_C Clamping Voltage** – Peak voltage measured across the TVS at a specified I_{ppm} (peak impulse current)
- I_R Reverse Leakage Current** – Current measured at V_R
- V_F Forward Voltage Drop for Uni-directional**

Ratings and Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

Figure 1 - TVS Transients Clamping Waveform

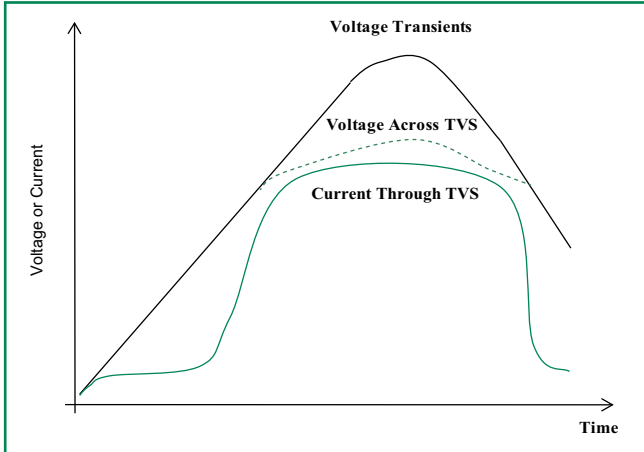


Figure 2 - Peak Pulse Power Rating

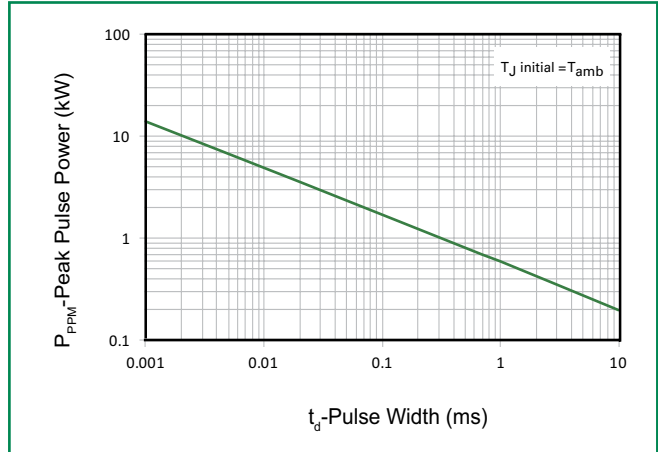


Figure 3 - Peak Pulse Power Derating Curve

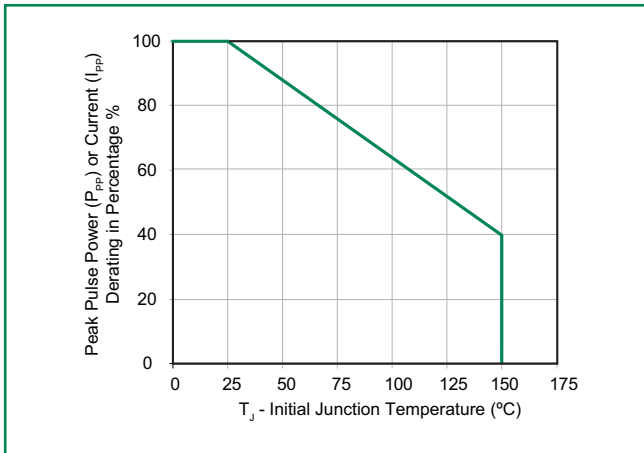


Figure 4 - Pulse Waveform

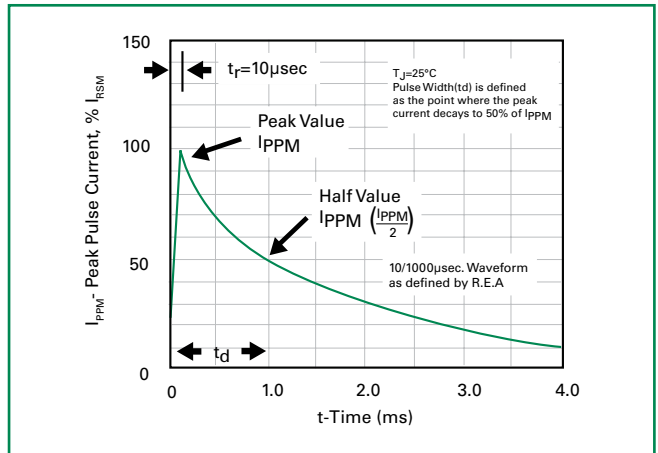


Figure 5 - Typical Junction Capacitance

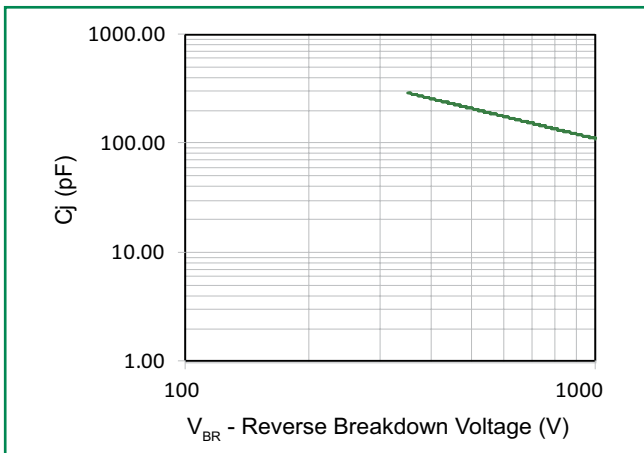


Figure 6 - Typical Transient Thermal Impedance

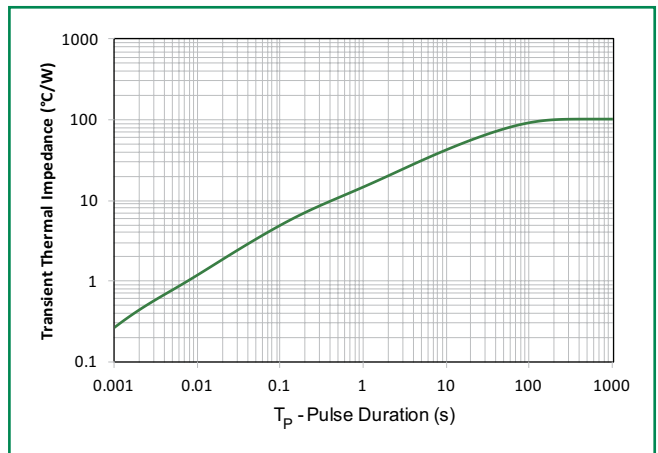


Figure 7 - Maximum Non-Repetitive Peak Forward Surge Current Uni-Directional Only

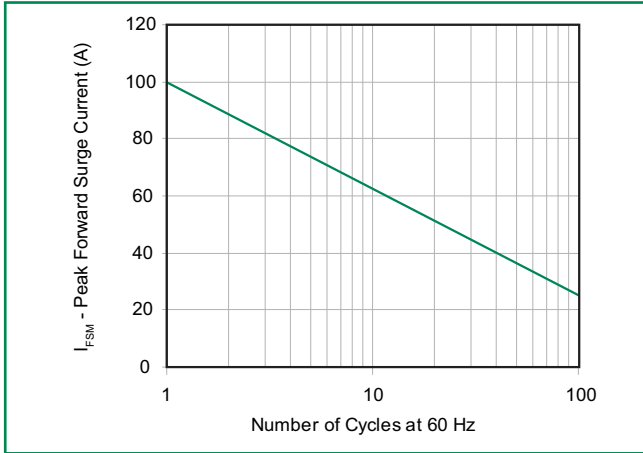
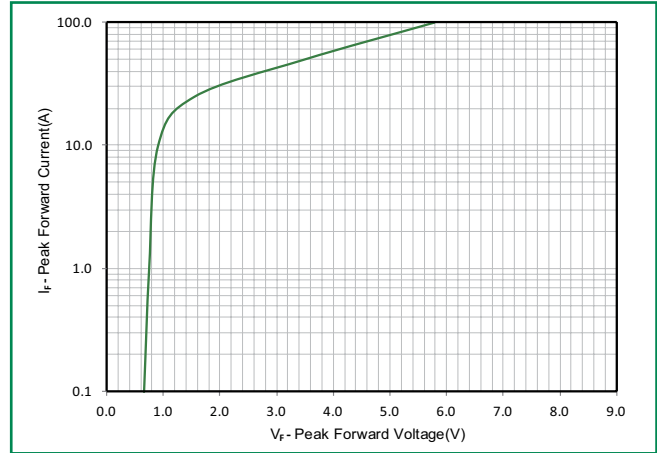
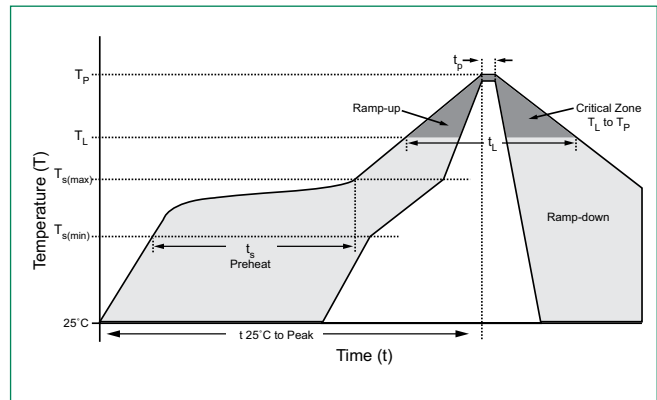


Figure 8 - Peak Forward Voltage Drop vs Peak Forward Current (Typical Values)



Soldering Parameters

Reflow Condition		Lead-free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_A) to peak)		3°C/second max
$T_{s(max)}$ to T_A - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_A) (Liquidus)	217°C
	- Time (min to max) (t_r)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Physical Specifications

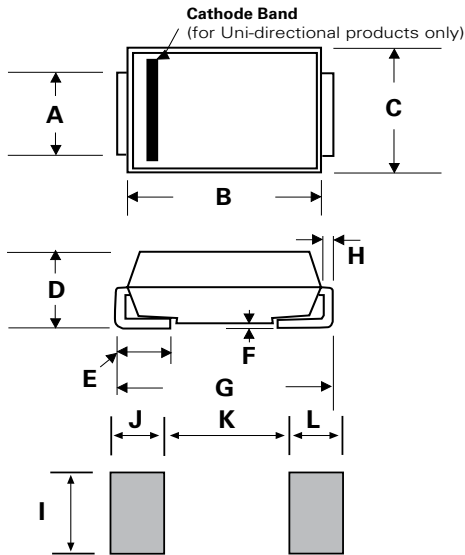
Weight	0.003 ounce, 0.093 grams
Case	JEDEC DO214AA. Molded plastic body over glass passivated junction
Polarity	Color band denotes cathode except Bidirectional
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102

Environmental Specifications

High Temp. Storage	JESD22-A103
HTRB	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111

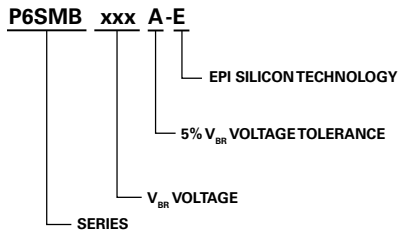
Dimensions

DO-214AA (SMB J-Bend)

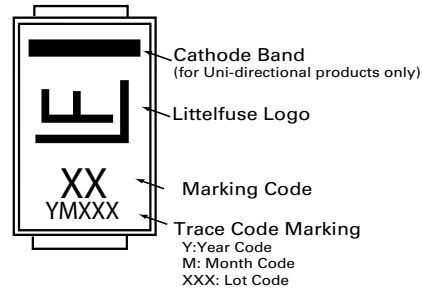


Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.076	0.086	1.930	2.200
B	0.160	0.187	4.060	4.750
C	0.130	0.155	3.300	3.940
D	0.078	0.103	1.990	2.610
E	0.030	0.060	0.760	1.520
F	-	0.008	-	0.203
G	0.205	0.220	5.210	5.590
H	0.006	0.012	0.152	0.305
I	0.089	-	2.260	-
J	0.085	-	2.160	-
K	-	0.107	-	2.740
L	0.085	-	2.160	-

Part Numbering System



Part Marking System



Packaging

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
P6SMBxxx A-E	DO-214AA	3000	Tape & Reel - 12mm tape/13" reel	EIA STD RS-481

Tape and Reel Specification

